2SK0123 (2SK123)

Silicon N-Channel Junction FET

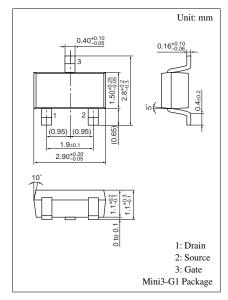
For impedance conversion in low frequency For electret capacitor microphone

■ Features

- lacktriangle High mutual conductance g_m
- Low noise voltage of NV

■ Absolute Maximum Ratings (T_a = 25°C)

| Parameter | Symbol | Ratings | Unit | |
|-------------------------------|------------------|-------------|------|--|
| Drain to Source voltage | V _{DSO} | 20 | V | |
| Drain to Gate voltage | V_{DGO} | 20 | V | |
| Drain to Source current | I_{DSO} | 2 | mA | |
| Drain to Gate current | I_{DGO} | 2 | mA | |
| Gate to Source current | I_{GSO} | 2 | mA | |
| Allowable power dissipation | P _D | 200 | mW | |
| Operating ambient temperature | T _{opr} | -20 to +80 | °C | |
| Storage temperature | T _{stg} | -55 to +150 | °C | |



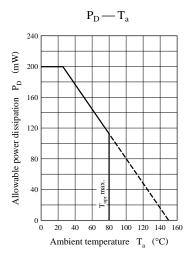
Marking Symbol: 1H Note: For the forming type, (Y) is indicated after the part No.

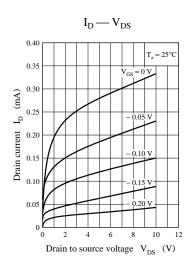
■ Electrical Characteristics $(T_a = 25^{\circ}C)$

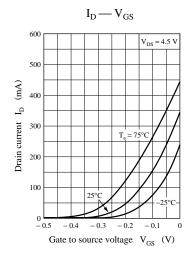
| Parameter | Symbol | Conditions | min | typ | max | Unit |
|---|----------------------------|---|------|-------|------|------|
| Current consumption | I_{D} | $V_D = 4.5 \text{ V}, C_O = 10 \text{ pF}, R_D = 2.2 \text{ k}\Omega \pm 1\%$ | 100 | | 600 | μΑ |
| Drain to Source cut-off current | I _{DSS} | $V_{DS} = 4.5 \text{ V}, V_{GS} = 0$ | 95 | | 480 | μΑ |
| Mutual conductance | g _m | $V_D = 4.5 \text{ V}, V_{GS} = 0, f = 1 \text{ kHz}$ | 0.7 | 1.6 | | mS |
| Noise figure N | NIV | $V_D = 4.5V, R_D = 2.2 \text{ k}\Omega \pm 1\%$ | | | 4 μ | μV |
| | INV | $C_O = 10 \text{ pF, A-curve}$ | | | | μν |
| $\begin{array}{c} G_{V1} \\ \\ G_{V2} \\ \\ G_{V3} \end{array}$ | G_{V1} | | -3 | 2 | | dB |
| | G _{V2} | $V_D = 4.5 \text{ V}, R_D = 2.2 \text{ k}\Omega \pm 1\%$ $C_O = 10 \text{ pF}, e_G = 10 \text{ mV}, f = 1 \text{ kHz}$ | 0 | 3.3 | | dB |
| | G _{V3} | $V_D = 12 \text{ V}, R_D = 2.2 \text{ k}\Omega \pm 1\%$ $C_O = 10 \text{ pF}, e_G = 10 \text{ mV}, f = 1 \text{ kHz}$ | -4.5 | - 0.3 | | dB |
| Voltage gain difference | $\Delta G_{V2} - G_{V1} $ | $V_D = 1.5 \text{ V}, R_D = 2.2 \text{ k}\Omega \pm 1\%$ | 0 | | +3.5 | dB |
| | $\Delta G_{V1} - G_{V3} $ | $C_O = 10 \text{ pF}, e_G = 10 \text{ mV}, f = 1 \text{ kHz}$ | 0 | | +3.5 | dB |

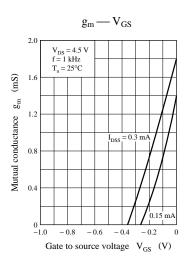
Note) The part number in the parenthesis shows conventional part number.

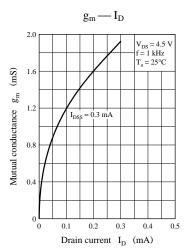
2SK0123 Panasonic











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